捷多邦,专业PCB打样工厂,24小时加急出货

查询2SC4860供应商

Ordering number:EN4580

NPN Epitaxial Planar Silicon Transistor

2SC4860



UHF Converter, Local Oscillator Applications

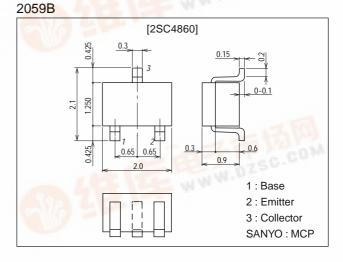
Features

- High cutoff frequency : $f_T=6.5$ GHz typ.
- · High gain : $|S^{2}1e|^{2}=11.5$ dB typ (f=1GHz).
- Small Cob : NF=0.65pF typ.

Package Dimensions

unit:mm

WW.DZSC.COM



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		10	V
Emitter-to-Base Voltage	VEBO		2	V
Collector Current	IC	The second se	30	mA
Collector Dissipation	PC	1 A. A. C.	150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ІСВО	V _{CB} =10V, I _E =0			1.0	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =5mA	60*		270*	ES IL
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =5mA		6.5	1	GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz	10-	0.65	1.1	pF
Forward Transfer Gain	S21e ²	V _{CE} =5V, I _C =5mA, f=1GHz	8	11.5	12.00	dB
Noise Figure	NF	V _{CE} =5V, I _C =5mA, f=1GHz	11.14	2.2	4.0	dB

* : The 2SC4860 is classified by 5mA h_{FE} as follows : 60 3 120 90 4 180 135 5 270

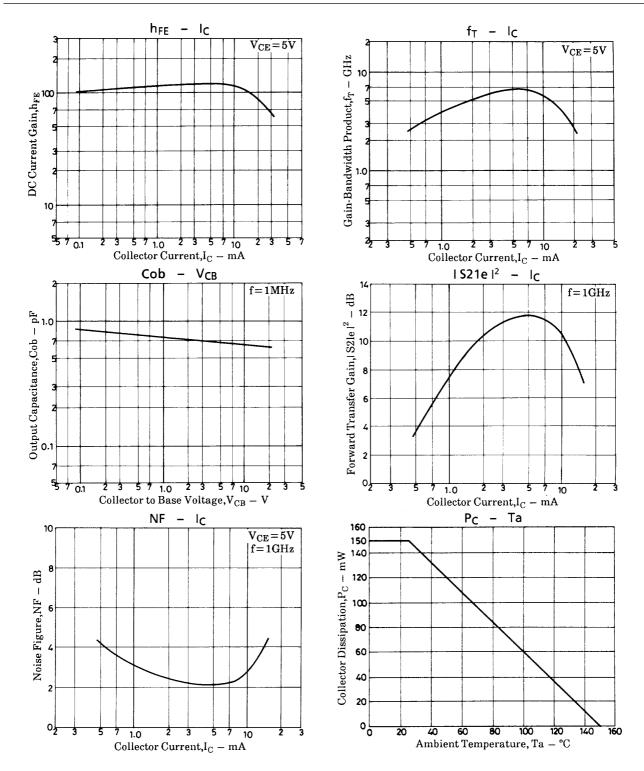
Marking : EN h_{FE} rank : 3, 4, 5

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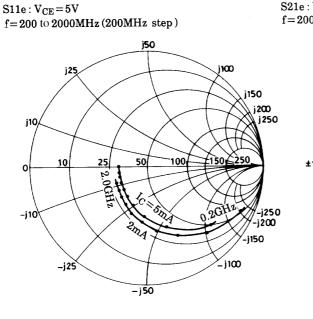
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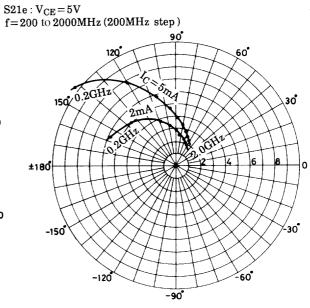
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

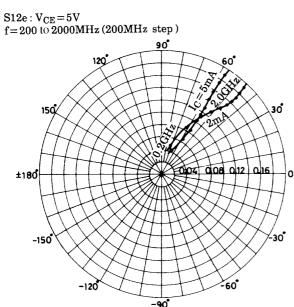
2SC4860



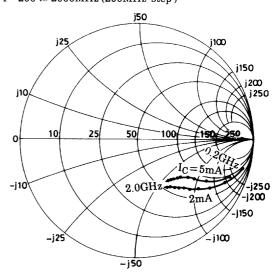
S parameter







 $S22e:V_{CE}\!=\!5V$ $f\!=\!200$ to 2000MHz (200MHz step)



S parameter (Common emitter)

 V_{CE} =5V, I_C =2mA, Z_O =50 Ω

-				•				•
Freq (MHz)	S ₁₁	∠s ₁₁	S ₂₁	∠s ₂₁	S ₁₂	∠s ₁₂	S ₂₂	∠ S ₂₂
200	0.888	-25.7	5.847	155.4	0.049	73.1	0.946	-14.8
400	0.765	-47.7	5.082	136.2	0.085	62.3	0.845	-25.6
600	0.645	-66.2	4.368	121.1	0.110	55.1	0.755	-32.7
800	0.553	-81.7	3.777	108.9	0.127	50.9	0.678	-37.8
1000	0.475	-95.5	3.281	98.5	0.141	47.8	0.625	-42.0
1200	0.419	-108.4	2.915	89.5	0.153	46.1	0.586	-45.0
1400	0.367	-120.1	2.593	81.5	0.162	45.3	0.553	-48.0
1600	0.337	-131.8	2.350	74.4	0.170	45.2	0.525	-50.7
1800	0.312	-141.7	2.141	69.2	0.180	45.5	0.501	-53.8
2000	0.297	-153.0	1.996	63.3	0.191	46.0	0.488	-56.3

V_{CE} =5V, I_C =5mA, Z_O =50 Ω

Freq (MHz)	S ₁₁	∠s ₁₁	S ₂₁	∠s ₂₁	S ₁₂	∠ S ₁₂	S ₂₂	∠ S ₂₂
200	0.737	-42.9	10.312	142.5	0.043	67.0	0.858	-21.1
400	0.540	-72.3	7.574	119.9	0.068	58.5	0.698	-29.9
600	0.418	-93.2	5.789	105.8	0.084	56.3	0.601	-33.4
800	0.349	-110.1	4.604	95.5	0.099	56.3	0.548	-35.7
1000	0.299	-125.4	3.885	87.1	0.114	56.6	0.518	-38.0
1200	0.275	-137.3	3.310	80.1	0.128	56.8	0.498	-39.9
1400	0.257	-149.9	2.906	73.6	0.142	57.2	0.480	-42.3
1600	0.249	-161.0	2.595	67.7	0.157	57.1	0.466	-45.5
1800	0.246	-170.2	2.346	63.6	0.172	57.1	0.450	-48.5
2000	0.245	179.7	2.174	58.4	0.189	56.7	0.447	-51.5

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